## NSN 5961-01-351-7212

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-351-7212 **Inclosure Material:** Ceramic and metal **Overall Length:** 92.0 millimeters **Overall Height:** 30.0 millimeters **Overall Width:** 20.0 millimeters **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device thyristor **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device thyristor Voltage Rating In Volts Per Characteristic: 1300.0 nonrepetitive peak reverse voltage all semiconductor device thyristor and 1200.0 repetitive peak off-state voltage all semiconductor device thyristor and 1200.0 repetitive peak reverse voltage all semiconductor device thyristor **Current Rating Per Characteristic:** 220.00 amperes forward current, total rms horsepower metric all semiconductor device thyristor and 140.00 amperes drain current universal all semiconductor device thyristor **Terminal Type And Quantity:** 3 screw and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: